GUJARAT TECHNOLOGICAL UNIVERSITY

BE - SEMESTER-III (NEW) EXAMINATION - WINTER 2017

Subject Code: 2131006 Date: 17/11/2017

Subject Name: Electronic Devices and Circuits

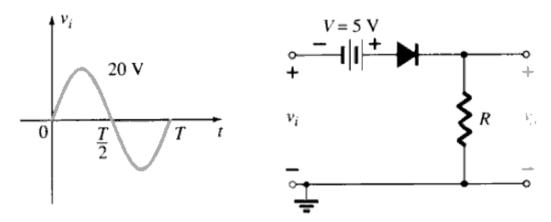
Time: 10:30 AM to 01:00 PM Total Marks: 70

Instructions:

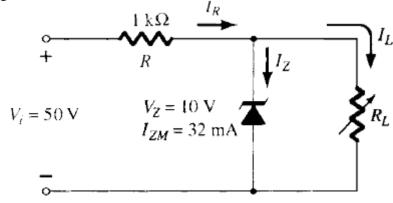
- 1. Attempt all questions.
- 2. Make suitable assumptions wherever necessary.
- 3. Figures to the right indicate full marks.

MARKS

- Q.1 (a) List the two types of carriers and name the type of impurity that causes each to be a majority carrier.
 - (b) With help of voltage doubler circuit, describe the action of voltage multipliers. 04
 - (c) A full-wave bridge rectifier with a 120 Vrms sinusoidal input has a load resistor of $1 \text{ k}\Omega$.
 - i) If Silicon diodes are employed, what is the dc voltage available at the load?
 - ii) Determine the required PIV rating of each diode.
 - iii) Find the maximum current through each diode during conduction.
 - iv) What is the required power rating of each diode?
- Q.2 (a) Draw a diode curve and label all significant points and areas.
 - (b) Determine the output waveform for the sinusoidal input of figure given below. 04



(c) For the network given below, determine the range of R_L and I_L that will result in V_{RL} being maintained at 10 V.



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	(c)	A transistor is connected in common emitter configuration in which collector supply is 8V and the voltage drop across resistance R_C connected in the collector circuit is 0.5V. The value of R_C =800 Ω , if α =0.96 determine: i) Collector emitter voltage ii) Base Current.	07	
Q.3	(a)	Drive the relation between dc alpha and dc beta for bipolar junction transistor.	03	
	(b)		04	
	(c)	Draw an emitter bias circuit and explain why it works well in amplifying circuits. OR	07	
Q.3	(a)	State the advantages of a Darlington transistor.	03	
	(b)		04 07	
	(c)	Calculate the divider current, base voltage, emitter voltage, emitter current, collector voltage, and collector-emitter voltage for an <i>npn</i> VDB circuit.	U7	
Q.4	(a)	Draw the symbol and list the application of	03	
		i) Step-recovery diode,		
		ii) Tunnel diode,		
		iii) PIN diode.	0.4	
	(b)	· · · · · · · · · · · · · · · · · · ·	04	
	(c)	frequency range. For the emitter-	07	
	(C)	follower network of	07	
		given figure below		
		determine: $R_{\rm p} \gtrsim 220 \mathrm{k}\Omega$		
		1) re,		
		ii) Z_i $V_i \circ \bigcap \beta = 100, r_o = \infty \Omega$		
		\mathbf{m} \mathbf{z}_0		
		iv) A_i 10 μ F		
		A		
		L'"		
		$R_E \lesssim 3.3 \text{ k}\Omega$		
		Z _e		
		+		
		OR		
Q.4	(a)	Differentiate between current shunt feedback and voltage shunt feedback.	03	
	(b)	Explain the JFET application as analog switch.	04	
	(c)	Draw diagrams that show common biasing arrangement of JFET and discuss	07	
		Drain curves.		
0.5	(c)	What is the use of Heat Sinks in power amplifier?	0.2	
Q.5	(a) (b)	What is the use of Heat Sinks in power amplifier? Calculate the gain of a negative feedback amplifier with an internal gain $A_v=75$	03 04	
	and feedback fraction $m_v = 1/15$. What will be the gain if A_v doubles?			
	(c)	Explain the characteristics and operation of enhancement-mode MOSFETs.	07	

OR

Q.5	(a)	a) List the advantages of Negative feedback.		
	(b)	Explain the role of coupling capacitor and bypass capacitor in amplifier circuit.		
	(c)	Draw a Schematic of a typical CMOS digital switching circuit and explain its	07	
		operation.		
